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Nanostructured CuO with a thin $q - C_3N_4$ layer as a highly efficient photocathode for solar water splitting†

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novel strategies for resolving problems associated with low-efficiency CuO photocathodes.

A g-C₃N₄/CuO nanostructure featuring improved photoelectrochemical properties was successfully prepared using a facile and cost-effective method involving electrodeposition and thermal oxidation. The improved photoelectrochemical properties were mainly ascribed to the increased surface area and improved charge transportation of the $g - C_3N_4/CuO$ photocathode. This photocathode can be used in Received 19th March 2021 Accepted 24th April 2021 DOI: 10.1039/d1ra02193a

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Introduction

In recent years, photoelectrochemical (PEC) water splitting has emerged as a promising technology for addressing the existing energy and environmental crises. This is because PEC water splitting shows tremendous potential for directly utilizing solar energy and offers useful, environmentally benign, clean energy.1,2 In particular, this process involves different types of semiconductors that are used to absorb photons, which are further converted into free–electron–hole pairs. Semiconductors such as $p\text{-G}aInP_2$, $p\text{-In}P$, $p\text{-}WSe_2$, $p\text{-}Si$, $p\text{-}CdS$, and $p\text{-}Ges_2$ type Cu_xO have been extensively explored for their use as potential PEC photocathodes.³⁻⁹ Among these, Cu_xO is one of the most promising candidates owing to its excellent characteristics; for instance, it features the most adequate bandgap in the visible region and a significantly low toxicity, and it can be prepared easily. Most importantly, it is abundant in the Earth's crust, which considerably lowers the overall cost of Cu_xO -based technologies. More specifically, compared to the widely investigated cuprous oxide $(Cu₂O)$, CuO is more thermodynamically stable. Moreover, unlike $Cu₂O$ with a bandgap of 2.1 eV, CuO with a direct bandgap of \sim 1.5 eV can absorb a vast majority of the solar spectrum. Therefore, CuO is a promising photocathode for achieving potentially higher solar conversion efficiencies than those afforded by $Cu₂O$ -based photocathodes.^{10,11} PAPER
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Despite these promising characteristics, few studies have investigated the use of CuO for PEC water splitting. This is mainly due to its low PEC activity that results from its low conductivity and carrier mobility, as well as its poor charge separation and transfer capabilities. Moreover, CuO experiences stability issues due to photocorrosion. Consequently, additional efforts are required to improve the PEC performance of CuO-based photocathodes and prevent or lessen their photocorrosion.

There are several possible approaches to address this, including defect engineering, the construction of junctions and Z-scheme systems, and the loading of cocatalysts. Additionally, changing the morphology and controlling the grain of ... are also viable options. $12-18$ In particular, the use of appropriate cocatalysts can significantly enhance the photocatalytic performance of CuO. This is because cocatalysts provide active sites while suppressing charge recombination and reverse reactions on the surface of CuO. Additionally, cocatalysts facilitate reactions by lowering the activation energy; therefore, they could further improve the kinetics of CuO-based water reduction.^{19,20} Hence, it is critical that novel, simple, and low-cost strategies are developed to accelerate electron–hole separation, which would enhance photocatalytic activity. Graphitic carbon nitride $(g-C_3N_4)$ has been widely demonstrated as a photocatalyst owing to its adequate band structure, high visible-light adsorption coefficient, low cost, and relatively high thermal stability.²¹⁻²⁶

Previous studies have focused on the heterostructure of g-C3N4/CuO to prevent the recombination of photogenerated carriers and improve the overall absorption of the composite in the visible-light region.²⁷⁻³³ However, reported $g - C_3N_4/CuO$ composites are almost all powder photocatalysts, which are difficult to separate from liquid systems. Furthermore, few studies have employed thin layers of $g - C_3N_4$ when developing photocathodes. Therefore, in this study, we developed a facile strategy for preparing a g-C3N4/CuO photocathode that is

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applicable to PEC water splitting. To ensure well-defined junctions were formed between $g - C_3N_4$ and CuO, Cu₂O was first fabricated via an electrodeposition method. Electrodeposition is preferred among the applicable techniques owing to its longterm stability, flexibility, relatively low cost, and good reproducibility of film properties. In addition, the morphology, structure, and orientation of the final products can be controlled when using this approach. A urea precursor for g- C_3N_4 was loaded onto the surface of the obtained Cu_2O . Finally, $g - C_3N_4/C$ uO was fabricated using thermal oxidation, which not only improves the film crystallinity but also increases the grain size of the CuO film.³⁴ The resultant $g-C_3N_4/CuO$ photocathode exhibited highly efficient PEC water-splitting performance. Moreover, this performance enhancement was investigated from the perspective of interfacial interactions using PEC measurements.

Results and discussion

The surface morphologies of the CuO and $g - C_3N_4/C$ uO thin films after thermal oxidation were observed via scanning electron microscopy (SEM). Fig. $1(a)$ shows that the CuO thin film has a small grain boundary with a size of \sim 1 µm. Unlike that of CuO, the surface of $g - C_3N_4/C$ uO exhibited a few humps

Fig. 1 Field-emission scanning electron microscopy (FE-SEM) images of (a) CuO and (b) g-C3N4/CuO. (c) Comparison of X-ray diffraction (XRD) patterns for Cu₂O, CuO, and $g - C_3N_4/CuO$.

(Fig. 1(b)). These are not due to $g - C_3N_4$ but rather selfassembled CuO, which is attributed to the large amount of urea used to prepare $g - C_3N_4/CuO$.⁷ From the cross-section SEM images, the CuO nanostructure was observed (Fig. S4†). The phase structures of the as-prepared Cu₂O, CuO, and $g - C_3N_4/$ CuO thin films were determined using X-ray diffraction (XRD) (Fig. 1(c)). The peak patterns were attributed to the monoclinic $Cu₂O$ and CuO phases. The main diffraction peaks observed for Cu₂O were at $2\theta = 37.52^\circ$ and 43.54° and correspond to the (111) and (200) planes, respectively, whereas the CuO peaks at $2\theta =$ 32.52° , 35.54° , and 38.72° correspond to the (110), (002), and (111) planes, respectively. After thermal oxidation, the $Cu₂O$ related peak was no longer observed, which further confirmed that $Cu₂O$ was converted to CuO. The characteristic peak of g- C_3N_4 was absent in the diffractogram of g- C_3N_4/CuO , which indicates that the concentration of $g - C_3N_4$ was significantly low, hindering its detection via XRD. This implies the formation of a considerably thin $g - C_3N_4$ layer. **PSC Articles** Operation and Creative Commons are the commons are the commons are formed the commons are commons are commons are commons are commons are the commons are commons are commons are commons are commons are commo

The nanostructure of this $g - C_3N_4/C$ uO thin film was then observed using transmission electron microscopy (TEM). The image in Fig. 2(a) is shaded to better distinguish CuO from g- C_3N_4 ; the former is lighter and the latter is darker due to their different electron penetrabilities. The TEM images indicate that the thin layer of $g - C_3N_4$ covers the entire surface of the CuO film. The thickness of the $g-C_3N_4$ layer is approximately 3 nm. The presence of this $g - C_3N_4$ layer on the surface of the CuO film was further confirmed using energy-dispersive X-ray spectrometry (EDS) elemental mapping (Fig. 2(b)). This mapping also shows that copper, oxygen, carbon, and nitrogen are present. These findings are also in agreement with the results obtained using an electron probe X-ray micro analyzer (Fig. S5†), which indicated the presence of $g-C_3N_4$ -related peaks (such as those of

Fig. 2 (a) Transmission electron microscopy (TEM) images and (b) the corresponding energy-dispersive X-ray spectrometry (EDS) mapping obtained from the $g - C_3N_4/C$ uO thin film.

carbon and nitrogen) and a low percentage of nitrogen. The formation of $g-C_3N_4/C$ uO thin films was further investigated via Fourier-transform infrared (FT-IR) analysis. The FT-IR spectra of the CuO and $g - C_3N_4/C$ uO thin films are presented in Fig. 3(a). The spectrum of CuO exhibits a band at 800 $\rm cm^{-1},$ which relates to the characteristic breathing mode of CuO.²⁸ For the $g-C_3N_4/$ CuO thin film, the bands between 3000 cm^{-1} and 3400 cm^{-1} are attributed to the N–H stretching vibration, whereas the bands over the range of 1100–1600 cm^{-1} are attributed to the C=N and C–N stretching vibration modes.²⁹ It is evident that the main characteristic bands of $g - C_3N_4$ appear in the spectrum of the g- C_3N_4/CuO thin film. The light absorption properties of the CuO and $g - C_3N_4$ /CuO thin films were characterized using UV-vis spectroscopy, as shown in Fig. 3(b). The optical band gap can be estimated by utilizing Tauc's equation, $(\alpha h\nu)^{1/n} = A(h\nu - E_{\rm g})$, in which α is the absorption coefficient, ÒF; is Planck's constant, ν is the light frequency, E_g is the bandgap energy, and A is a constant. For direct transition, the value of n is $1/2$. The

Fig. 3 (a) Fourier-transform infrared (FT-IR) spectra, (b) UV-vis spectra and (c) Tauc plots for the CuO and $g - C_3N_4/CuO$ thin films.

corresponding Tauc plots are represented in Fig. 3(c). The CuO film demonstrated an absorption edge at 950 nm, and its E_{φ} value was calculated to be 1.30 eV using the Kubelka–Munk theory. The $g - C_3N_4/C$ uO thin film featured an absorption edge

Fig. 4 High-resolution X-ray photoelectron spectroscopy (XPS) spectra of Cu 2p for (a) CuO and (b) g-C3N4/CuO films and of O 1s for (c) CuO and (d) $g - C_3N_4/C$ uO films.

at 930 nm, with its E_g calculated to be 1.33 eV. Based on it being slightly reduced in the visible light range, we concluded that the thin layer of $g - C_3N_4$ on CuO does not interfere with the absorption of light.

The chemical states of CuO and $g - C_3N_4/C$ uO were determined using X-ray photoelectron spectroscopy (XPS), and the Gaussian–Lorentzian method was employed for analyzing the spectral regions of the XPS survey (Fig. 4). The overall spectrum primarily comprises two regions that represent the Cu 2p (970– 925 eV) and O 1s (540–526 eV) spin–orbit levels. Fig. 4(a) and (b) display the high-resolution spectrum of Cu 2p, separated into Cu $2p^{3/2}$ and Cu $2p^{1/2}$ peaks at 933.8 eV and 953.8 eV, respectively. Additional confirmation regarding the CuO state is obtained from the broad satellite peaks at a higher binding energy than the main peaks. The main peak of Cu $2p^{3/2}$ at 933.8 eV is accompanied by two satellite peaks toward higher binding energies of approximately 943.8 eV and 941.5 eV, which suggests that CuO is completely converted from $Cu₂O$ by thermal oxidation.30,31 The XPS O 1s spectra are presented in Fig. 4(c) and (d). The notable peak at 529 eV can be attributed to O^{2-} in CuO and g-C₃N₄/CuO. The fitted spectra of the O 1s spectra display four peaks centered at 529.5 eV, 530.0 eV, 531.6 eV, and 533.0 eV, which correspond to the metal oxide, surface hydroxyl group, $C=O$, and $C-O$, respectively. The peak intensity for the hydroxyl-group peak in the spectrum of the g- C_3N_4/CuO thin film is higher than that of the hydroxyl-group peak in the spectrum of the CuO thin film. This implies that $g - C_3N_4$ /CuO contains more hydroxyl groups on its surface than CuO does. This could enhance the reaction site, where electrons react with protons in the electrolyte. Therefore, $g - C_3N_4/CuO$ can **BSC** Advances
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provide a better reaction sites for hydrogen generation than those provided by CuO.

To assess the PEC ability of the CuO and $g - C_3N_4/CuO$ photocathodes, a three-electrode configuration was used. Fig. 5(a) depicts the chopped photocurrent of the samples from 0 V to 0.6 V vs. the reversible hydrogen electrode (RHE) with light on/off intervals of 1 s. The photocurrent density of $g - C_3N_4/$ CuO was -0.85 mA cm⁻² at 0 V (vs. the RHE), which was 1.5 times greater than that of CuO $(-0.5 \text{ mA cm}^{-2})$.

To better understand the enhancement afforded to the photocathode by $g - C_3N_4/CuO$, electrochemical impedance spectroscopy (EIS) was used to evaluate the interface reaction between the photocathode and the electrolyte. EIS measurements were conducted at a frequency range of 10^5 to 10^{-1} Hz. As shown in Fig. 5(b), semicircles can be clearly distinguished in the Nyquist plots for each sample. These were used to understand the charge transfer process at the electrode–electrolyte interface, where the semicircle diameter is equivalent to the charge transfer resistance $(R_{\text{ct}})^{15}$ The R_{ct} of the g-C₃N₄/CuO photocathode is lower than that of the CuO photocathode, which indicates that $g - C_3N_4$ reduces the charge transfer process at the interface between the CuO surface and the electrolyte. Hence, $g - C_3N_4$ plays a significant role in accelerating the charge separation and transfer at the interface, thereby enhancing PEC performance.

The flat-band potential (V_{fb}) and carrier density (N_{d}) of the CuO and $g-C_3N_4/CuO$ nanostructured photocathodes were determined using Mott-Schottky (MS) measurements at a fixed frequency of 1 kHz. The $1/C^2$ variable can be determined using eqn (1):

Fig. 5 Photoelectrochemical properties of the photocathode: (a) the linear sweep voltammogram plots under chopped illumination with 1 s light on/off intervals, (b) Nyquist plots, (c) Mott–Schottky (MS) plots, (d) incident photon-to-current conversion efficiencies (IPCEs), (e) linear voltammograms obtained in the dark and under illumination, and (f) applied bias photon-to-current efficiencies (ABPEs) of the CuO and g-C₃N₄/ CuO films.

Fig. 6 Amperometric $(i-t)$ curves of the Cu₂O, CuO, and g-C₃N₄/CuO photocathodes under visible-light irradiation.

$$
\frac{1}{C^2} = \frac{2}{\varepsilon \varepsilon_0 e N_\text{A}} \left[(V - V_\text{fb}) - \frac{k_\text{B} T}{e} \right],\tag{1}
$$

where C is the depletion capacitance of the semiconductor layer, V is the applied potential at the electrode, N_A is the acceptor concentration, e is the elemental charge value, ε_0 is the permittivity of the vacuum, ε is the dielectric constant of the semiconductor, T is the absolute temperature, and k_B is the Boltzmann constant. The V_{fb} can be obtained from the intercept of the plot tangents with the potential axis $(1/C^2 = 0)$. As shown in Fig. 5(c), the MS plots of both photocathodes exhibit a negative slope, verifying their p-type semiconductor behavior. This indicates that $g - C_3N_4$ does not change the p-type characteristic of the photocathode, which is due to its low thickness. However, it is evident that the hole concentration of the $g-C_3N_4/CuO$ electrode improves significantly, as evidenced by the gentler slope of the MS plot of the $g - C_3N_4/CuO$ photocathode in comparison to that of the CuO photocathode. The values of V_{fb} for the CuO and $g - C_3N_4/C$ uO photocathodes were calculated to be 0.8 and 1.0, respectively, vs. the RHE. If the V_{fb} value shifts toward the balance band, this would cause an increase in the hole concentration of the g-C₃N₄/CuO photocathode. Based on these results, the presence of the thin layer of $g - C_3N_4$ enables more efficient electron transfer between CuO and the electrolyte and lowers the redox activity at the $g - C_3N_4/CuO$ surface. Therefore, the higher photocurrent exhibited by the $g - C_3N_4/CuO$ photocathode can be explained by the high concentration and separation efficiency of the photogenerated electron–hole pairs. Fig. 5(d) shows the incident photon-to-current conversion efficiencies (IPCEs) of the CuO and $g - C_3N_4/C$ uO thin films, which were analyzed to explore their external and internal quantum efficiencies at a potential of 0 V vs. the RHE. This would allow us to describe the photocurrent density as a function of wavelength. In general, the IPCE value is described by the following equation (eqn (2)): Paper $\frac{1}{2}$ As the photosal of the published on 2021. This are every in the set of th

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I PCE = \frac{1240 \times J}{\lambda \times P_{\text{light}}},\tag{2}
$$

where J is the photocurrent density (mA cm $^{-2})$ and λ is the wavelength of the illumination. It is evident that the IPCE of g- C_3N_4/CuO is higher than that of CuO over the entire wavelength range evaluated. This implies that the former possesses a higher quantum efficiency than that of the latter. Fig. 5(e) shows the increase in photocurrent density (from -0.53 to -0.93 mA cm⁻² at 0 V vs. RHE) that resulted from applying the $g-C_3N_4$ cocatalyst. Additionally, the applied bias photon-to-current efficiencies (ABPEs) of the samples are displayed in Fig. 5(f). A maximum efficiency of 0.12% was noted for $g - C_3N_4/CuO$ and that of CuO was 0.08% (both at 0.24 V vs. RHE).

Fig. 6 shows the stability of the Cu₂O, CuO, and $g - C_3N_4/CuO$ thin films under an applied potential of $0 \nabla \nu s$. RHE. Although the Cu₂O thin film exhibits the highest photocurrent density among the three films, its photostability degrades rapidly. Meanwhile, the CuO thin film features a lower photocurrent density than that of the $Cu₂O$ thin film and its photostability remains consistent. The photocurrent of the $g - C_3N_4/CuO$ thin film was also maintained for 4000 s. This indicates that $g - C_3N_4$ can improve the photocatalytic properties of ... while maintaining photostability.

Conclusions

A g-C3N4/CuO nanostructure was fabricated via electrodeposition and thermal oxidation. The XRD pattern confirmed the monoclinic phase of the CuO film, while the TEM and FT-IR results revealed that a significantly thin $g - C_3N_4$ layer was successfully formed over the surface of the CuO film. In addition, the MS results demonstrated the p-type nature of the CuO and $g - C_3N_4/CuO$ thin films. Based on the XPS results, the g- C_3N_4/CuO thin film features more reaction sites than the CuO thin film does. Moreover, according to the EIS results, the transfer resistance of the $g - C_3N_4/C$ uO thin film is lower than that of the CuO thin film. The PEC properties of the $g - C_3N_4/CuO$ photocathode are superior to those of the CuO photocathode due to the benefits provided by $g - C_3N_4$, namely the increased surface area and the improved charge separation and transfer efficiency across the thin films and the electrode-electrolyte interface. Moreover, the stability of the $g-C_3N_4/CuO$ photocathode suggests that $g - C_3N_4$ is highly suitable as a direct protection layer. The results of this work suggest that $g - C_3N_4$ is a suitable, potential catalyst for PEC water splitting.

Materials and methods

Preparation of $Cu₂O$ thin film

Fluoride-doped tin oxide (FTO) on a glass substrate (surface resistivity: \sim 8–9 Ω) was used as the substrate. The FTO was cleaned via sonication for 5 min in ethanol, isopropyl alcohol (IPA), and deionized (DI) water before being dried using a N_2 gas gun. Initially, 0.5 M $Cu₂SO₄·5H₂O$ in 40 mL of DI water was mixed with 12 mL of lactic acid. The solution was stirred until it was fully mixed. Subsequently, 7 g of NaOH was added while stirring until a clear solution was obtained and the pH was just over 11. For the electrodeposition of $Cu₂O$, a three-electrode configuration was used, in which the working electrode was the FTO substrate, the reference electrode (RE) was Ag/AgCl in saturated KCl, and the counter electrode (CE) was a Pt wire. The cleaned FTO samples were dipped into the solution, and a potential of -0.6 V vs. Ag/AgCl was applied for 1 h at 60 °C without stirring. The residue on the surface of the samples was rinsed using DI water and then dried in air. To prepare CuO, the samples were annealed in a muffle furnace at 520 $^{\circ}$ C for 3 h under an air atmosphere (with a ramping rate of 5 $^{\circ} \mathrm{C}$ min $^{-1}$).

Preparation of $g - C_3N_4/C$ uO thin film

A conventional thermal condensation method with urea as a precursor was used to synthesize $g - C_3N_4$. Before placing Cu_2O in the muffle furnace to prepare CuO, a diluted solution of urea in methanol was prepared by adding 2 g of urea to 10 mL of methanol, which was then stirred for 1 h at room temperature. The CuO samples were subsequently dipped into the solution for 30 min, and the urea precursor formed as a self-condensate on the CuO surface. All the prepared samples were then placed into crucibles with covers and annealed at 520 \degree C for 3 h in a muffle furnace. The $g - C_3N_4/C$ uO thin film was ready for use after being cooled to room temperature. **PSC** Advances Common Pearator (Equilibrary Article). The Common Common Pearator Common Pearator Common Commo

Characterization A D2 phaser XRD diffractometer (Bruker AXS Analytical Instruments Pvt. Ltd., Germany) was used to record XRD patterns of the samples, and an X'PERT PRO MRD PW3388/60 at the Energy Convergence Core Facility in Chonnam National University was used for confirming the structure and phase composition. The morphology of the samples was analyzed using field-emission SEM (FE-SEM) and TEM. FT-IR spectra were measured in the range 400–4000 cm^{-1} using a Spectrum 400 instrument. UV-vis spectra were determined using UV-vis spectroscopy (UV-2450). PEC analysis was carried out using a potentiostat (Parstat 4000). The PEC cell consisted of Ag/AgCl as the RE, a Pt wire as the CE, and the fabricated photocathode as the working electrode; the electrolyte was N₂-saturated 0.1 M Na₂SO₄. A 300 W xenon lamp (Newport) was used for the light illumination experiments, and the light that was chopped onto the photocathodes was calibrated to simulate AM 1.5 illumination (1 sun). All potentials were referenced to the RHE according to the following relationship: $V_{\text{RHE}} = V_{\text{Ag/AgCl}} + 0.197 \text{ V} + 0.059 \text{ V} \times \text{pH}.$

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

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